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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Hiroshi HASHIMOTO et al.**

Group Art Unit: **2813**

Application Number: **10/756,403**

Examiner: **James M. Mitchell**

Filed: **January 14, 2004**

Confirmation Number: **3499**

For: **METHOD OF PRODUCING SEMICONDUCTOR DEVICE**

Attorney Docket Number: **042017**

Customer Number: **38834**

INFORMATION DISCLOSURE STATEMENT  
UNDER 37 C.F.R. §1.97(b)

Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

January 10, 2006

Sir:

In compliance with 37 C.F.R. §1.56, Applicants direct the attention of the Patent and Trademark Office to the documents listed on the attached PTO/SB/08. This paper is being filed within the time periods set forth in 37 C.F.R. §1.97(b). A copy of each non-U.S. document is enclosed herewith, together with a Japanese Office Action.

If there are any fees due in connection with the filing of this paper, please charge Deposit Account No. 50-2866.

Respectfully submitted,

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Enclosures: PTO/SB/08

Japanese Office Action dated December 13, 2005

3 Documents

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

(use as many sheets as necessary)

Sheet

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of

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First Named Inventor	Hiroshi HASHIMOTO et al.
Art Unit	2813
Examiner Name	James M. Mitchell
Attorney Docket Number	042017

**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code <sup>2</sup> (if known)		
	1	US 6,388,504		05-14-2002	Goto et al.
	2	US 6,664,148		12-16-2003	Goto et al.
		US			
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation <sup>6</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)			
	3	JP	2002-151598		05-24-2002	Mitsubishi Electric Corp	Abstract & Trans
	4	JP	02-271659		11-06-1990	Fujitsu Ltd.	Abstract & Trans
	5	JP	2001-156260		06-08-2001	NEC Corp	Abstract & Trans

**NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation <sup>6</sup>

Examiner Signature

Date Considered

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kind Codes of USPTO Patent Documents at [www.uspto.gov](http://www.uspto.gov), MPEP 901.04 or in the comment box of this document. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to indicate here if English language Translation is attached.